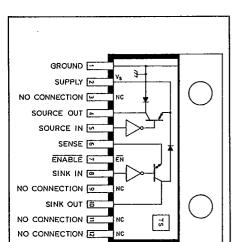
HIGH-CURRENT HALF-BRIDGE POWER DRIVER



Dwg. PP-023

ABSOLUTE MAXIMUM RATINGS at $T_1 \le 150^{\circ}C$

Supply Voltage, V _S 40 V
Output Current, I _{OUT} ±6.0 A
Input Voltage, V _{IN}
Sense Voltage, V _{SENSE}
Package Power Dissipation,
P _D See Graph
Operating Temperature Range,
T _A 20°C to + 85°C
Storage Temperature Range,
T55°C to + 150°C

Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of conditions, do not exceed the specified output current rating or a junction temperature of +150°C.

The UDN2955W-2 half-bridge power driver combines a highcurrent, half-bridge power driver with low-level control and protection circuitry. For PWM applications there are provisions for output current sensing and an ENABLE (active low) input. The output can source or sink up to 6 A continuously. This device features a minimum breakdown and sustaining voltage of 40 V. It can be used in pairs for fullbridge operation or in triplets for 3-phase brushless dc motors.

Protection is included which shuts down the device during overtemperature conditions caused by loss of cooling; internal flyback and clamp diodes are included for switching inductive loads. Internal logic lockout and delays prevent potentially destructive crossover currents. The logic inputs are compatible with TTL and 5 V CMOS logic systems.

A similar device, excluding the ENABLE and output current sensing provision, in a 5-lead TO-220 style package, is the UDN2951Z-2.

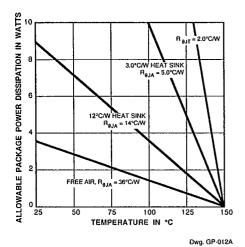
The UDN2955W-2 is supplied in a 12-lead power-tab single in-line plastic package. The tab is at ground potential, allowing multiple devices to share a common heat sink.

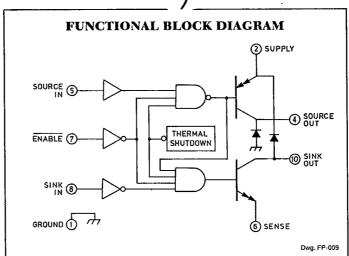
FEATURES

- ± 6 A Continuous Output Current
- Output Voltage to 40 V
- Internal Thermal Shutdown
- TTL and 5 V CMOS Compatible Inputs
- Integral Transient-Suppression Diodes

Always order by complete part number: UDN2955W-2 .

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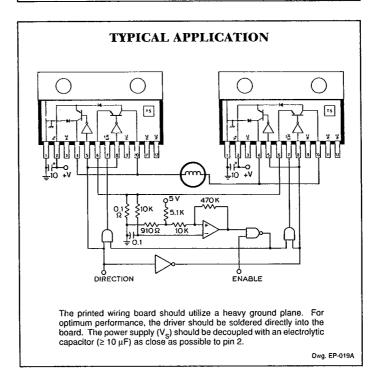




TRUTH TABLE

	INPUTS	OUTPUTS			
ENABLE	SOURCE	SINK	SOURCE	SINK	
Low	Low	Low	OFF	ON	
Low	Low	High	OFF	OFF	
Low	High	Χ	ON	OFF	
High	Х	Х	OFF	OFF	

X = Irrelevant



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ELECTRICAL CHARACTERISTICS at $T_A = +25^{\circ}C$, $T_J \le +150^{\circ}C$, $V_S = 40 \text{ V}$

	Symbol			Limits			
Characteristic		Test Conditions	Min.	Тур.	Max.	Units	
Functional Supply Range	V _s		10	_	40	٧	
Output Leakage Current	I _{CEX}	SINK _{OUT} = 40 V,		-			
		SOURCE _{IN} = 0.8 V, SINK _{IN} = 2.0 V	-	<1.0	50	μА	
		SOURCE _{OUT} = 0 V,		-			
		SOURCE _{IN} = 0.8 V, SINK _{IN} = 2.0 V		<-1.0	- 50	μА	
Output Sustaining Voltage	V _{CE(sus)}	$I_{OUT} = \pm 6.0 \text{ A, L} = 10 \text{ mH}$	40		_	٧	
Output Saturation Voltage	V _{CE(SAT)}	SINK _{OUT} = 5.0 A			1.5	٧	
		SINK _{OUT} = 6.0 A		_	2.0	V	
		SOURCE _{OUT} = -5.0 A	-		2.0	V	
		SOURCE _{OUT} = -6.0 A			2.5	V	
Input Voltage	Logic 1	SOURCE _{IN} or SINK _{IN}	2.0	_	_	V	
	Logic 0	SOURCE _{IN} or SINK _{IN}		_	0.8	V	
Input Current	Logic 1	SOURCE _{IN} or SINK _{IN} = 2.0 V	_	3.0	10	μА	
	Logic 0	SOURCE _{IN} or SINK _{IN} = 0.8 V	_	-1.0	-10	μА	
Propagation Delay	t _{PHL}	Sink Driver (includes Turn-On Delay)		2.5		μs	
		Source Driver	<u> </u>	2.5		μs	
	t _{PLH}	Sink Driver	1-	0.2	_	μs	
		Source Driver (includes Turn-On Delay)	7 -	2.5		μs	
Supply Current	I _{S(ON)}	SOURCE _{IN} = 2.0 V	_	10	15	mA	
		SOURCE _{IN} = SINK _{IN} = 0.8 V	_	20	25	mA	
	I _{S(OFF)}	SOURCE _{IN} = 0.8 V, SINK _{IN} = 2.0 V	—	8.0	10	mA	
Flyback Diode Forward Voltage	V _F	I _F = 6.0 A	+		2.8	V	
Clamp Diode Forward Voltage	V _F	I _F = 6.0 A	+-		2.1	V	
Diode Leakage Current	I _R	Each Diode, V _B = 40 V	_	<1.0	50	μА	
Thermal Shutdown	T _J		<u> </u>	165		°C	

NOTE: Typical Data is given for circuit design information only.

Negative current is defined as coming out of (sourcing) the specified device pin.